

# **SI4463BDY-T1-GE3**

### SI4463BDY-T1-GE3 Information

| with the sener.com | <br>SI4463BDY-T1-GE3<br>Vishay Siliconix<br>Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single<br>MOSFET P-CH 20V 9.8A 8SOIC<br>8-SOIC (0.154", 3.90mm Width)<br>For the pricing/inventory/lead time, please contact |                 |
|--------------------|---|-----------------|
| For Reference Only | us<br>Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com   | Request a Quote |

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### SI4463BDY-T1-GE3 Specifications

| Manufacturer Part Number               | SI4463BDY-T1-GE3                     |
|--|--------------------------------------|
| Manufacturer                           | Vishay Siliconix                     |
| Category                               | Discrete Semiconductor Products      |
|  | Transistors - FETs, MOSFETs - Single |
| Package                                | 8-SOIC (0.154", 3.90mm Width)        |
| Series                                 | TrenchFET?                           |
| FET Type                               | P-Channel                            |
| Technology                             | MOSFET (Metal Oxide)                 |
| Drain to Source Voltage (Vdss)         | 20V                                  |
| Current - Continuous Drain (Id) @ 25°C | 9.8A (Ta)                            |
| Drive Voltage (Max Rds On, Min Rds On) | 2.5V, 10V                            |
| Vgs(th) (Max) @ Id                     | 1.4V @ 250µA                         |
| Gate Charge (Qg) (Max) @ Vgs           | 56nC @ 4.5V                          |
| Input Capacitance (Ciss) (Max) @ Vds   | -                                    |
| Vgs (Max)                              | ±12V                                 |
| FET Feature                            | -                                    |
| Power Dissipation (Max)                | 1.5W (Ta)                            |
| Rds On (Max) @ Id, Vgs                 | 11 mOhm @ 13.7A, 10V                 |
| Operating Temperature                  | -55°C ~ 150°C (TJ)                   |
| Mounting Type                          | Surface Mount                        |
| Supplier Device Package                | 8-SO                                 |
| Package / Case                         | 8-SOIC (0.154", 3.90mm Width)        |
|  | Report errors?                       |

### SI4463BDY-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### SI4463BDY-T1-GE3 Payment Methods





If you have any question about SI4463BDY-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com